HEWLETT® PACKARD

Power MOSFET/IGBT Gate Drive Optocouplers

Technical Data

HCPL-3100
HCPL-3101

Features

- **High Output Current**
  I_{O1} and I_{O2} (0.4 A Peak, 0.1 A Continuous)
- **1.5 kV/μs Minimum Common Mode Rejection (CMR) at V_{CM} = 600 V**
- **Wide Operating V_{CC} Range (15 to 30 Volts)**
- **High Speed**
  1 μs Typical Propagation Delay (HCPL-3100)
  0.3 μs Typical Propagation Delay (HCPL-3101)
- **Recognized under UL 1577 for Dielectric Withstand Proof Test Voltages of 5000 Vac, 1 Minute**

Applications

- **Isolated MOSFET/IGBT Gate Drive**
- **AC and DC Motor Drives**
- **General Purpose Industrial Inverters**
- **Uninterruptable Power Supply**

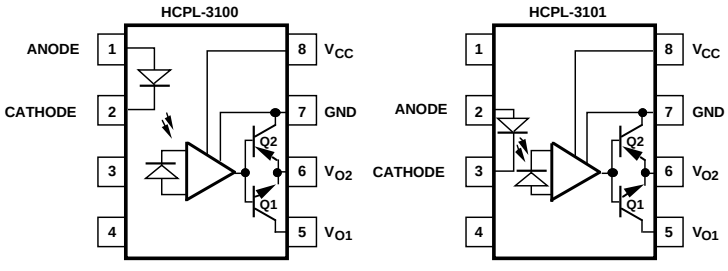
Description

The HCPL-3100/3101 consists of an LED* optically coupled to an integrated circuit with a power output stage. These optocouplers are suited for driving power MOSFETs and IGBTs used in motor control inverter applications. The high operating voltage range of the output stage provides the voltage drives required by gate controlled devices. The voltage and current supplied by these optocouplers allow for direct interfacing to the power device without the need for an intermediate amplifier stage.

The HCPL-3100 switches a 3000 pF load in 2 μs and the HCPL-3101, using a higher speed LED, switches a 3000 pF load in 0.5 μs. With a CMR rating of 5 kV/μs typical these optocouplers readily reject transients found in inverter applications.

The LED controls the state of the output stage. Transistor Q2 in the output stage is on with the LED off, allowing the gate of the power device to be held low. Turning on the LED turns off transistor Q2 and switches on transistor Q1 in the output stage which provides current and voltage to drive the gate of the power device.

Functional Diagram



TRUTH TABLE

LED	OUTPUT	Q1	Q2
ON	HIGH LEVEL	ON	OFF
OFF	LOW LEVEL	OFF	ON

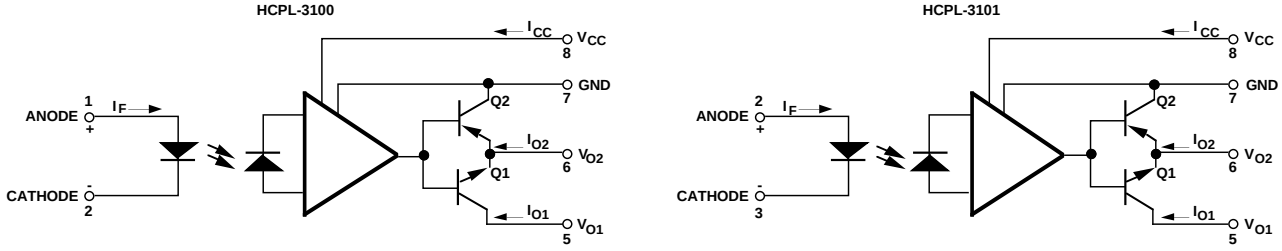
THE USE OF A 0.1 μF BYPASS CAPACITOR CONNECTED BETWEEN PINS 8 AND 7 IS RECOMMENDED. ALSO CURRENT LIMITING RESISTOR IS RECOMMENDED (SEE FIGURE 1, AND NOTE 2 AND NOTE 7).

*HCPL-3100 LED contains Silicon-doped GaAs and HCPL-3101 LED contains AlGaAs.

CAUTION: It is advised that normal static precautions be taken in handling and assembly of this component to prevent damage and/or degradation which may be induced by ESD.

5965-3583E

Schematic



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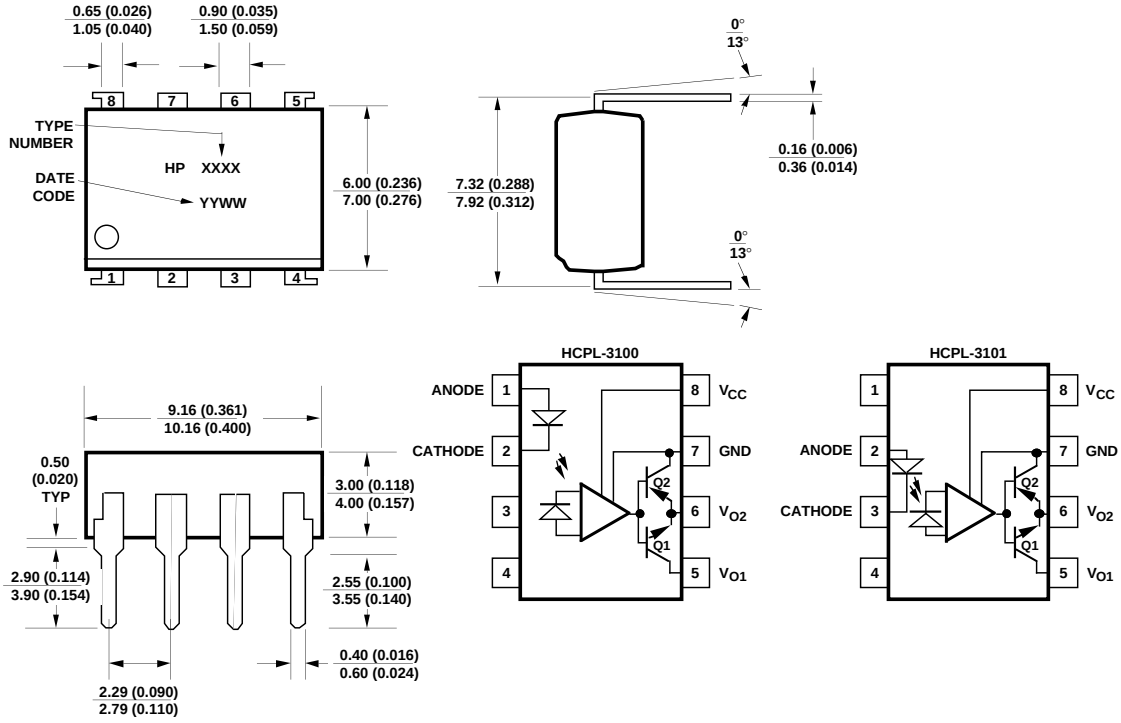
Outline Drawing



Demonstrated ESD Performance

Human Body Model: MIL-STD-883 Method 3015.7: Class 2

Machine Model: EIAJ IC-121-1988 (1988.3.28 Version 2), Test Method 20, Condition C: 1200 V

Regulatory Information

The HCPL-3100/3101 has been approved by the following organization:

UL

Recognized under UL 1577, Component Recognition Program, File E55361.

Insulation and Safety Related Specifications

Parameter	Symbol	Value	Units	Conditions
Min. External Air Gap (External Clearance)	L(IO1)	6.0	mm	Shortest distance measured through air, between two conductive leads, input to output
Min. External Tracking Path (External Creepage)	L(IO2)	6.0	mm	Shortest distance path measured along outside surface of optocoupler body between input and output leads
Min. Internal Plastic Gap (Internal Clearance)		0.15	mm	Through insulation distance conductor to conductor inside the optocoupler cavity

Absolute Maximum Ratings

Parameter		Symbol	Device	Min.	Max.	Unit	Conditions	Fig.	Note
Storage Temperature		T_S		-55	125	°C			
Operating Temperature		T_A		-25	80	°C			
Input	Continuous Current	I_F	HCPL-3100		25	mA		11	1
			HCPL-3101		20	mA		11	1
	Reverse Voltage	V_R			6	V	T_A = 25°C		
Supply Voltage		V_{CC}			35	V			
Output 1	Continuous Current	I_{O1}			0.1	A			1
	Peak Current				0.4	A	Pulse Width < 0.15 µs, Duty cycle = 1%		1
	Voltage	V_{O1}			35	V			
Output 2	Continuous Current	I_{O2}			0.1	A			1
	Peak Current				0.4	A	Pulse Width < 0.15 µs, Duty cycle = 1%		1
Output Power Dissipation		P_O			500	mW		12	1
Total Power Dissipation		P_T			550	mW		12	1
Lead Solder Temperature		260°C for 10 s, 1.0 mm below seating plane							

Recommended Operating Conditions

Parameter	Symbol	Device	Min.	Max.	Units
Power Supply Voltage	V_{CC}		15	30*	V
			15	24	V
Input Current (ON)	$I_{F(ON)}$	HCPL-3100	12**	24	mA
		HCPL-3101	8**	16	mA
Input Current (OFF)	$I_{F(OFF)}$	HCPL-3100	-	0.6	mA
		HCPL-3101	-	0.2	mA
Operating Temperature	T_A		-25	80	°C

*For T_A = -10°C to 60°C.
**The initial switching threshold is 10 mA or less for the HCPL-3100 and 5 mA or less for the HCPL-3101.

Recommended Protection for Output Transistors

During switching transitions, the output transistors Q1 and Q2 of the HCPL-3100/3101 can conduct large amounts of current. Figure 1 describes a recommended circuit design showing a current limiting resistor R_2 which is necessary in order to prevent damage to the output transistors Q1 and Q2. (See Note 7.) A bypass capacitor C_1 is also recommended to reduce power supply noise.

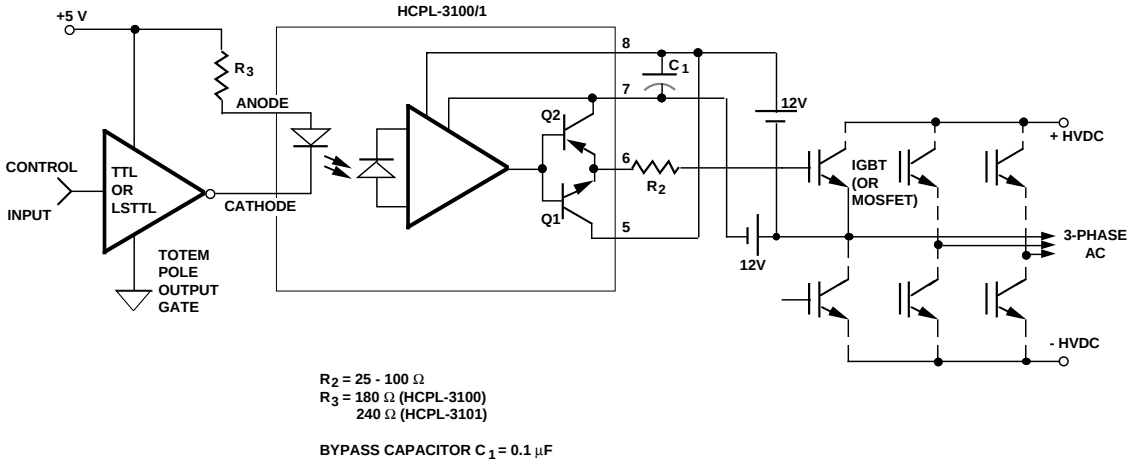


Figure 1. Recommended Output Transistor Protection and Typical Application Circuit.

Electrical Specifications

Over recommended temperature (T_A = -25°C to +80°C) unless otherwise specified.

Parameter		Sym.	Device	Min.	Typ.	Max.	Units	Test Conditions		Fig.	Note
Input Forward Voltage		V_F	HCPL-3100	-	1.2	1.4	V	I_F = 20 mA	T_A = 25°C	13	
				0.6	0.9	-	V	I_F = 0.2 mA			
			HCPL-3101	-	1.6	1.75	V	I_F = 10 mA		14	
				1.2	1.5	-	V	I_F = 0.2 mA			
Input Reverse Current		I_R	HCPL-3100	-	-	10	µA	V_R = 4 V	T_A = 25°C		
			HCPL-3101					V_F = 5 V			
Input Capacitance		C_{IN}		-	30	250	pF	V_F = 0 V, f = 1 kHz, T_A = 25°C			
Output 1	Low Level Voltage	V_{O1L}	HCPL-3100	-	0.2	0.4	V	I_F = 10 mA	V_{CC1} = 12 V, I_{O1} = 0.1 A, V_{CC2} = -12 V	2, 17, 18	2
			HCPL-3101					I_F = 5 mA			
	Leakage Current	I_{O1L}		-	-	500	µA	V_{CC} = V_{O1} = 35 V, V_{O2} = 0 V, I_F = 0 mA, T_A = 25°C		5	
Output 2	High Level Voltage	V_{O2H}	HCPL-3100	18	21	-	V	I_F = 10 mA	V_{CC} = 24 V, V_{O1} = 24 V, I_{O2} = -0.1 A	3, 19, 20	2
			HCPL-3101					I_F = 5 mA			
	Low Level Voltage	V_{O2L}		-	1.2	2.0	V	V_{CC} = V_{O1} = 24 V, I_{O2} = 0.1 A, I_F = 0 mA		4, 21, 22	
	Leakage Current	I_{O2L}	HCPL-3100	-	-	500	µA	I_F = 10 mA	V_{CC} = 35 V, V_{O2} = 35 V, T_A = 25°C	6	
			HCPL-3101					I_F = 5 mA			
Supply Current	High Level	I_{CCH}	HCPL-3100	-	6	10	mA	T_A = 25°C	V_{O1} = 24 V	7, 23	2
				-	-	14	mA	V_{CC} = 24 V, I_F = 10 mA			
			HCPL-3101	-	6	10	mA	T_A = 25°C	V_{O1} = 24 V		
				-	-	14	mA	V_{CC} = 24 V, I_F = 5 mA			
	Low Level	I_{CCL}		-	8	13	mA	T_A = 25°C	V_{O1} = 24 V	7, 24	
				-	-	17	mA	V_{CC} = 24 V, I_F = 0 mA			
Low to High Threshold Input		I_{FLH}	HCPL-3100	1.0	4.0	7.0	mA	T_A = 25°C		8, 15, 16	2, 3
				0.6	-	10.0	mA	V_{CC} = V_{O1} = 24 V			
			HCPL-3101	0.3	1.5	3.0	mA	T_A = 25°C			
				0.2	-	5.0	mA	V_{CC} = V_{O1} = 24 V			

Switching Specifications (T_A = 25°C)

Parameter	Sym.	Device	Min.	Typ.	Max.	Units	Test Conditions		Fig.	Note
Propagation Delay Time to High Output Level	t_{PLH}	HCPL-3100	-	1	2	µs	I_F = 10 mA	V_{CC} = 24 V, V_{O1} = 24 V, R_G = 47 Ω, C_G = 3000 pF	9, 25, 26, 27	2, 6
		HCPL-3101	-	0.3	0.5	µs	I_F = 5 mA			
Propagation Delay Time to Low Output Level	t_{PHL}	HCPL-3100	-	1	2	µs	I_F = 10 mA			
		HCPL-3101	-	0.3	0.5	µs	I_F = 5 mA			
Rise Time	t_r	HCPL-3100	-	0.2	0.5	µs	I_F = 10 mA			
		HCPL-3101					I_F = 5 mA			
Fall Time	t_f	HCPL-3100	-	0.2	0.5	µs	I_F = 10 mA			
		HCPL-3101					I_F = 5 mA			
Output High Level Common Mode Transient Immunity	$\|CM_H\|$	HCPL-3100	1500	5000	-	V/µs	I_F = 10 mA	V_{CM} = 600 V (peak), V_{CC} = 24 V V_{O1} = 24 V $\Delta V_{02H} = \Delta V_{02L}$ = 2.0 V	10	2
		HCPL-3101					I_F = 5mA			
Output Low Level Common Mode Transient Immunity	$\|CM_L\|$		1500	5000	-	V/µs	I_F = 0 mA			

Packaging Characteristics

Parameter	Sym.	Min.	Typ.	Max.	Units	Test Conditions	Fig.	Note
Input-Output Momentary Withstand Voltage*	V_{ISO}	5000			V rms	RH = 40% to 60% t = 1 min, T_A = 25°C		4, 5
Resistance (Input-Output)	R_{I-O}	$5x10^{10}$	10^{11}	–	Ω	V_{I-O} = 500 V, T_A = 25°C RH = 40% to 60%		4
Capacitance (Input-Output)	C_{I-O}	–	1.2	–	pF	f = 1 MHz		4

*The Input-Output Momentary Withstand Voltage is a dielectric voltage rating that should not be interpreted as an input-output continuous voltage rating. For the continuous voltage rating refer to the VDE 0884 Insulation Characteristics Table (if applicable), your equipment level safety specification, or HP Application Note 1074, "Optocoupler Input-Output Endurance Voltage."

Notes:

1. Derate absolute maximum ratings with ambient temperatures as shown in Figures 11 and 12.
2. A bypass capacitor of 0.01 µF or more is needed near the device between V_{CC} and GND when measuring output and transfer characteristics.
3. I_{FLH} represents the forward current when the output goes from low to high.
4. Device considered a two terminal device; pins 1-4 are shorted together and pins 5-8 are shorted together.
5. For devices with minimum V_{ISO} specified at 5000 V rms, in accordance with UL 1577, each optocoupler is proof-tested by applying an insulation test voltage ≥ 6000 V rms for one second (leakage current detection limit, $I_{I-O} \leq$ 200 µA).
6. The t_{PLH} and t_{PHL} propagation delays are measured from the 50% level of the input pulse to the 50% level of the output pulse.
7. R_2 limits the Q1 and Q2 peak currents. For more applications and circuit design information see Application Note "Power Transistor Gate/Base Drive Optocouplers."

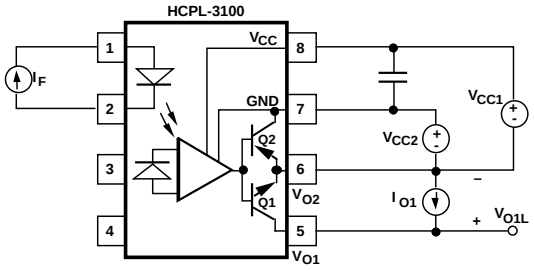


Figure 2. Test Circuit for Low Level Output Voltage V_{O1L}.

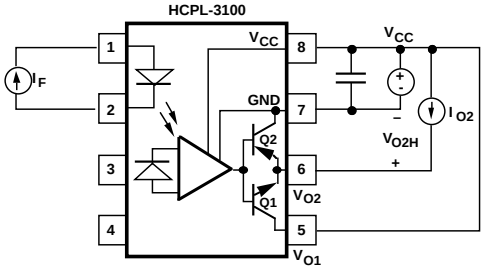


Figure 3. Test Circuit for High Level Output Voltage V_{O2H}.

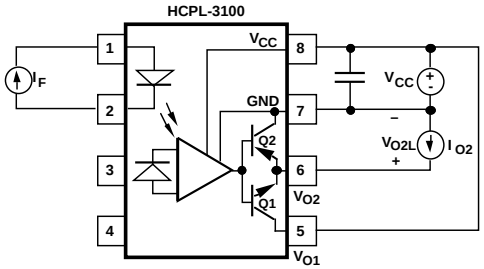


Figure 4. Test Circuit for Low Level Output Voltage V_{O2L}.

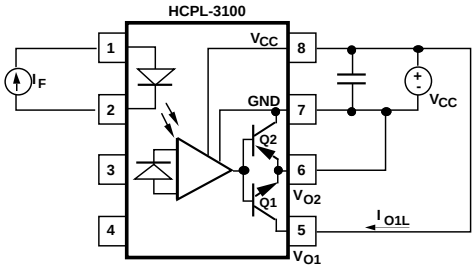


Figure 5. Test Circuit for Leakage Current I_{O1L}.

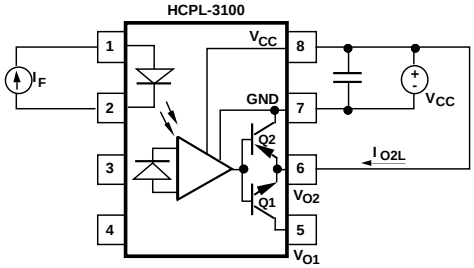


Figure 6. Test Circuit for Leakage Current I_{O2L}.

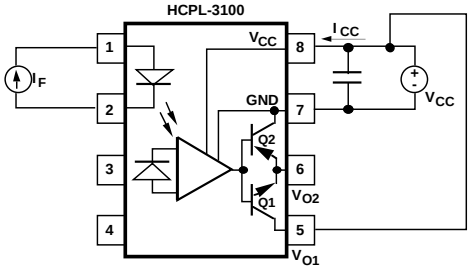


Figure 7. Test Circuit for I_{CCH} and I_{CCL}.

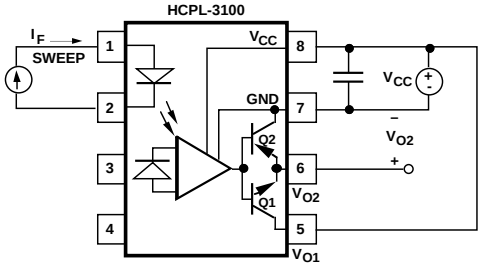


Figure 8. Test Circuit for Threshold Input Current I_{FLH}.

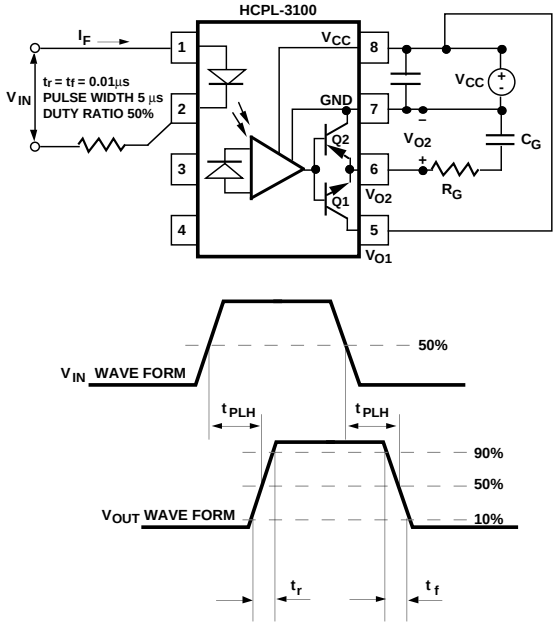


Figure 9. Test Circuit for t_{PLH}, t_{PHL}, t_r, and t_f.

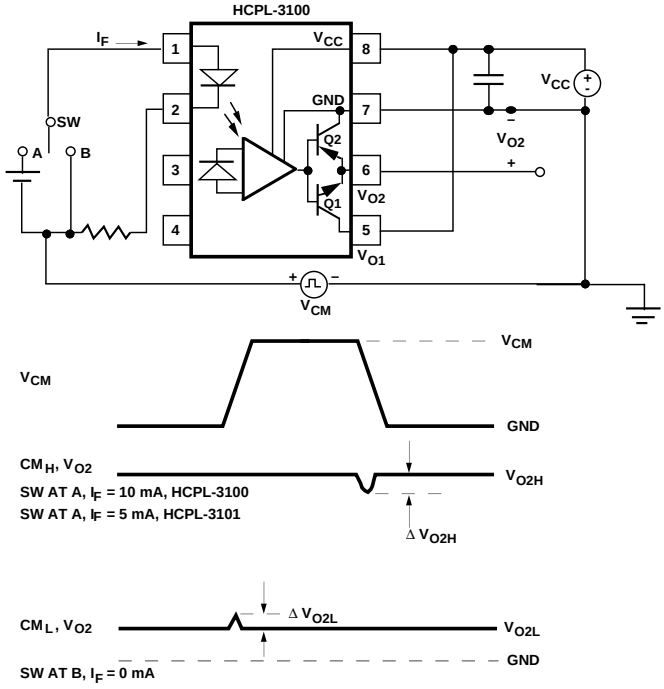


Figure 10. Test Circuit for CM_H and CM_L.

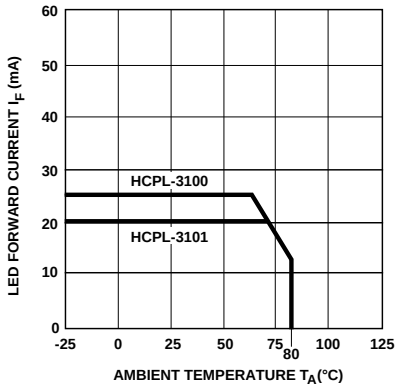


Figure 11. LED Forward Current vs. Ambient Temperature.

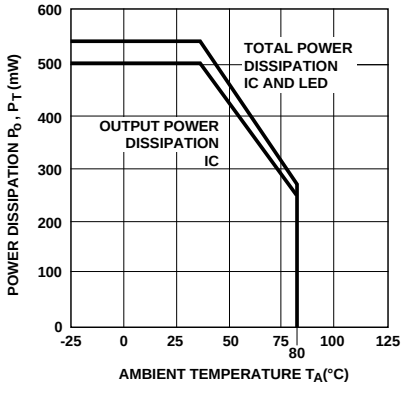


Figure 12. Maximum Power Dissipation vs. Ambient Temperature.

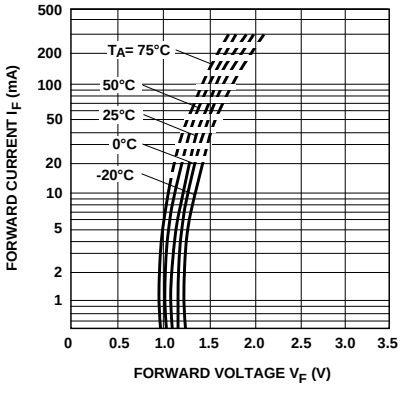


Figure 13. Typical Forward Current vs. Forward Voltage, HCPL-3100.

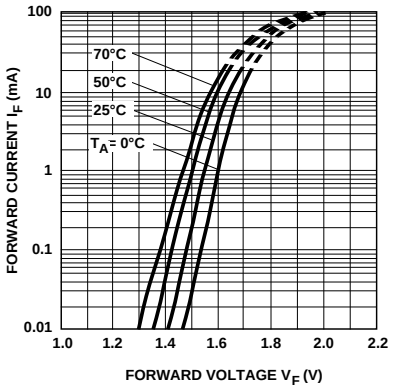


Figure 14. Typical Forward Current vs. Forward Voltage, HCPL-3101.

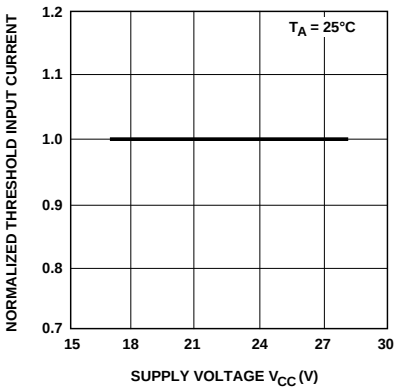


Figure 15. Normalized Low to High Threshold Input Current vs. Supply Voltage.

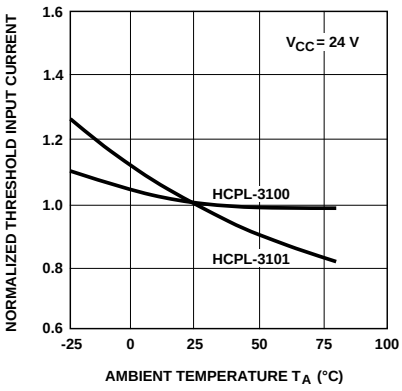


Figure 16. Normalized Low to High Threshold Input Current vs. Ambient Temperature.

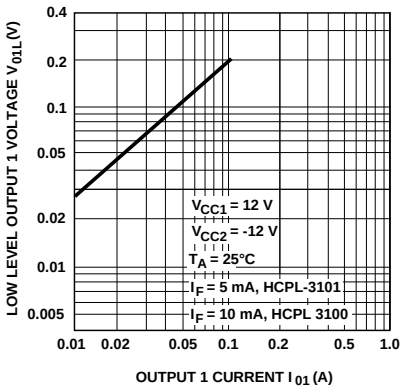


Figure 17. Typical Low Level Output 1 Voltage vs. Output 1 Current.

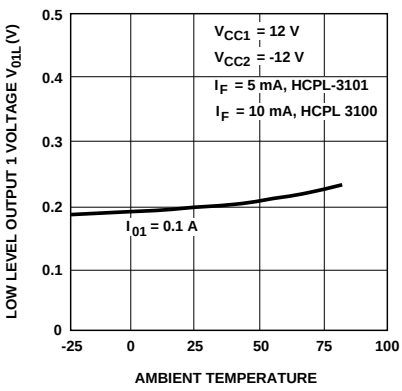


Figure 18. Typical Low Level Output 1 Voltage vs. Ambient Temperature.

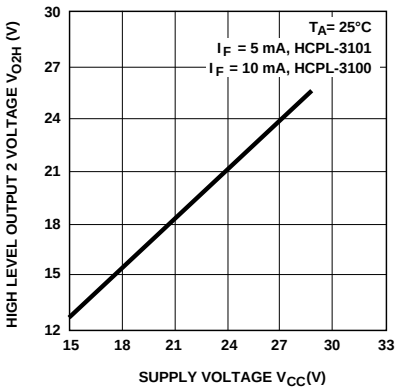


Figure 19. Typical High Level Output 2 Voltage vs. Supply Voltage.

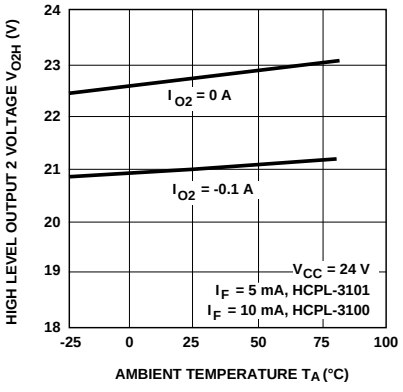


Figure 20. Typical High Level Output 2 Voltage vs. Ambient Temperature.

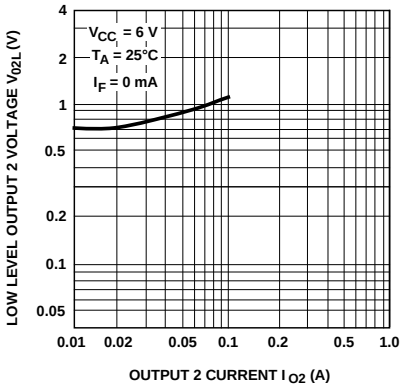


Figure 21. Typical Low Level Output 2 Voltage vs. Output 2 Current.

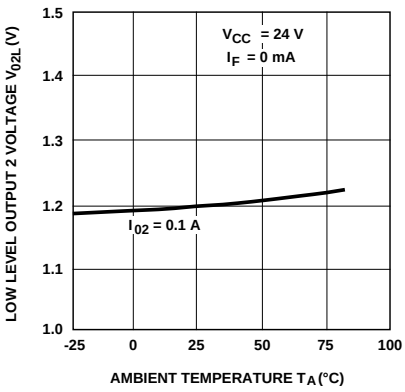


Figure 22. Typical Low Level Output 2 Voltage vs. Ambient Temperature.

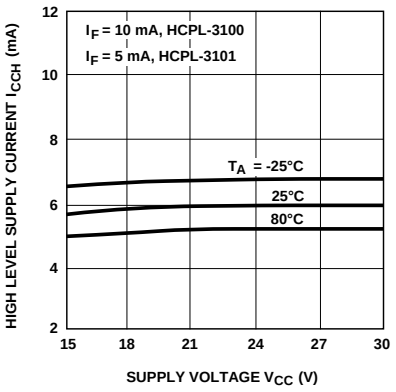


Figure 23. Typical High Level Supply Current vs. Supply Voltage.

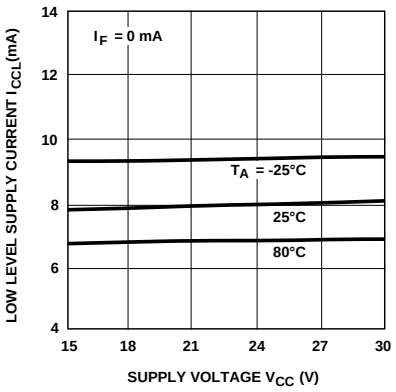


Figure 24. Typical Low Level Supply Current vs. Supply Voltage.

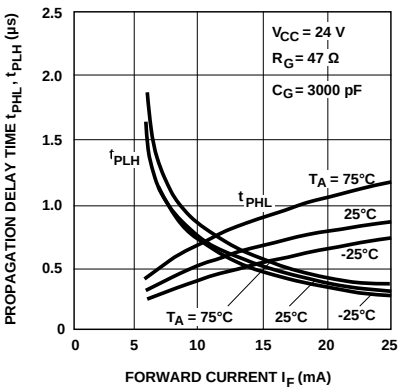


Figure 25. Typical Propagation Delay Time vs. Forward Current, HCPL-3100.

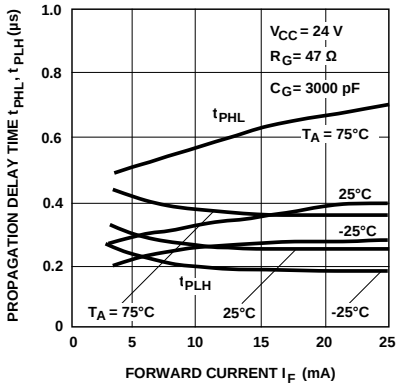


Figure 26. Typical Propagation Delay Time vs. Forward Current, HCPL-3101.

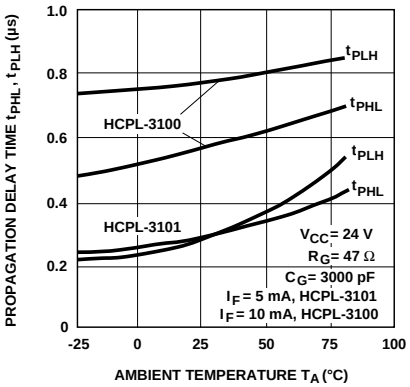


Figure 27. Typical Propagation Delay Time vs. Ambient Temperature.